

PJQ2566A

60V N-Channel Enhancement Mode MOSFET

Voltage	60 V	Current	20 A
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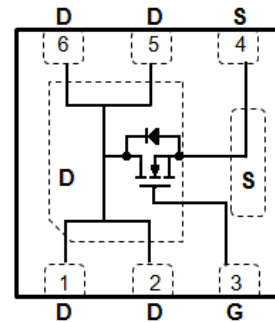
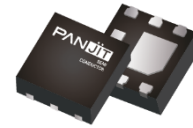
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@10A<14m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@6A<21m\Omega$
- Excellent FOM
- Logic Level Drive
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN2020B-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0086 grams

DFN2020B-6L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	$T_C=25^\circ\text{C}$	I_D	20	A
	$T_C=100^\circ\text{C}$		12.7	
Pulsed Drain Current ^(Note 1)	$T_C=25^\circ\text{C}$	I_{DM}	80	
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	9.6	W
	$T_C=100^\circ\text{C}$		3.8	
Continuous Drain Current ^(Note 4)	$T_A=25^\circ\text{C}$	I_D	8.4	A
	$T_A=70^\circ\text{C}$		6.7	
Power Dissipation	$T_A=25^\circ\text{C}$	P_D	1.7	W
	$T_A=70^\circ\text{C}$		1.1	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ\text{C}$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	13	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	75	

PJQ2566A

Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1	1.4	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =10A	-	11.2	14	mΩ
		V _{GS} =4.5V, I _D =6A	-	16.3	21	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q _g	V _{DS} =30V, I _D =10A, V _{GS} =10V (Note 2,3)	-	16.7	22	nC
Gate-Source Charge	Q _{gs}		-	3.3	-	
Gate-Drain Charge	Q _{gd}		-	4	-	
Input Capacitance	C _{iss}	V _{DS} =30V, V _{GS} =0V, f=1MHz	-	834	1168	pF
Output Capacitance	C _{oss}		-	323	485	
Reverse Transfer Capacitance	C _{rss}		-	18	-	
Gate resistance	R _g	f=1MHz	-	1.3	-	Ω
Turn-On Delay Time	t _{d(on)}	V _{DS} =30V, I _D =10A, V _{GS} =10V, R _G =3Ω (Note 2,3)	-	7	-	ns
Turn-On Rise Time	t _r		-	20	-	
Turn-Off Delay Time	t _{d(off)}		-	17	-	
Turn-Off Fall Time	t _f		-	16	-	
Drain-Source Diode						
Diode Forward Current	I _S	T _C =25°C	-	-	20	A
Pulsed Diode Forward Current	I _{SM}		-	-	80	
Diode Forward Voltage	V _{SD}	I _S =10A, V _{GS} =0V	-	0.85	1.3	V
Reverse Recovery Time	T _{rr}	V _{DD} =30V, V _{GS} =0V	-	40	-	ns
Reverse Recovery Charge	Q _{rr}	I _S =10A, dI _S /dt=100A/us	-	21	-	nC

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an R_{θJC}=13°C/W.
4. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
5. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J=25°C.
6. Guaranteed by design, not subject to production testing.

PJQ2566A

TYPICAL CHARACTERISTIC CURVES

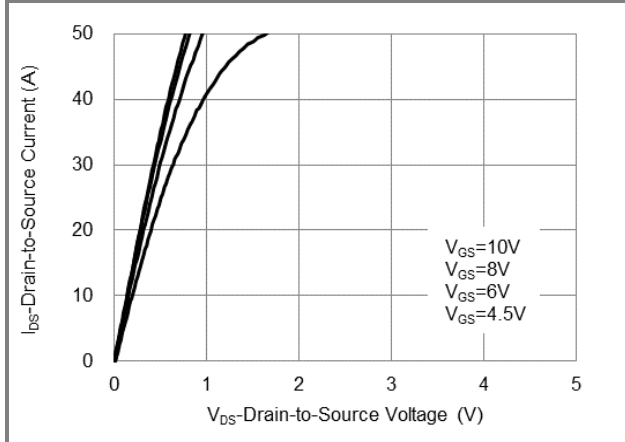


Fig.1 On-Region Characteristics

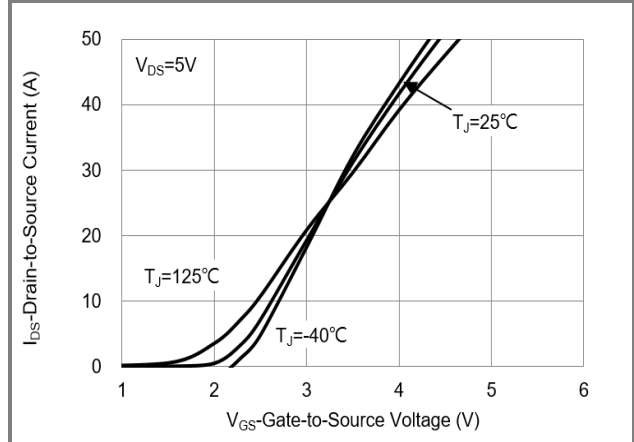


Fig.2 Transfer Characteristics

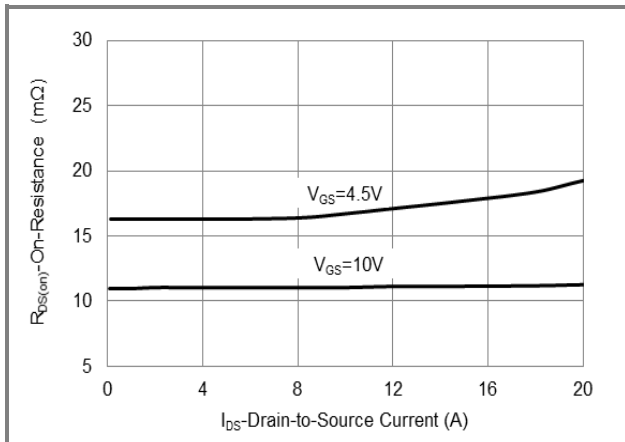


Fig.3 On-Resistance vs. Drain Current

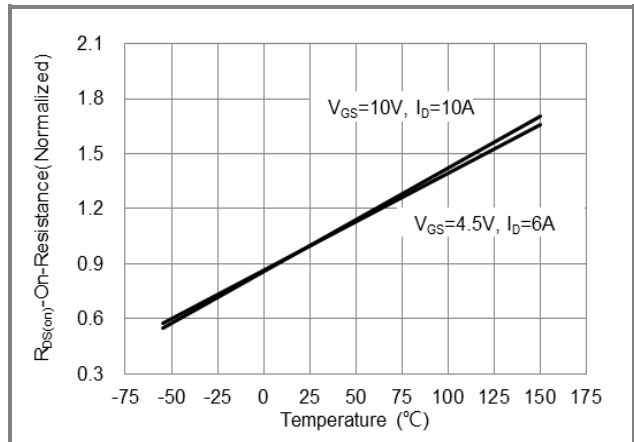


Fig.4 On-Resistance vs. Junction temperature

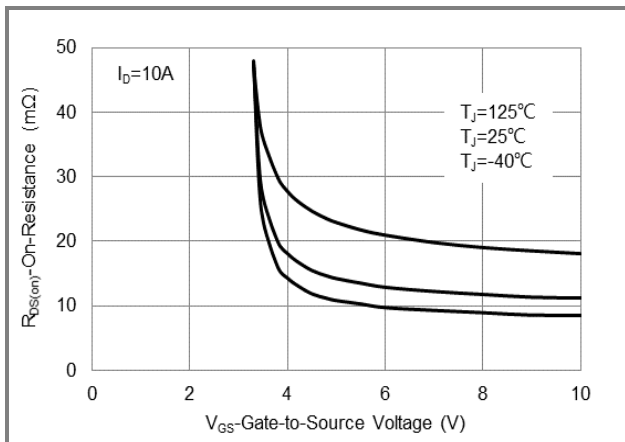


Fig.5 On-Resistance Variation with Vgs

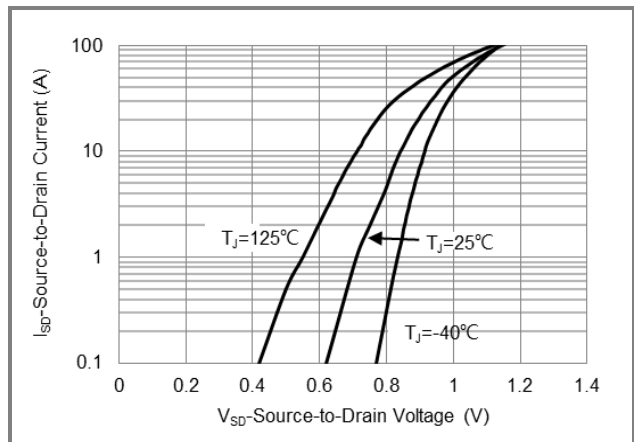


Fig.6 Source-Drain Diode Forward Voltage

PJQ2566A

TYPICAL CHARACTERISTIC CURVES

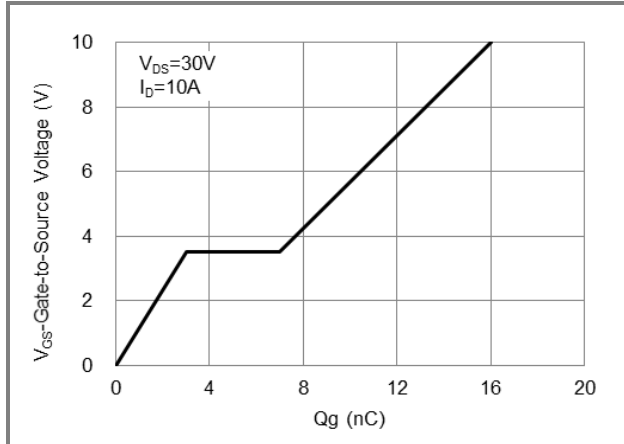


Fig.7 Gate-Charge Characteristics

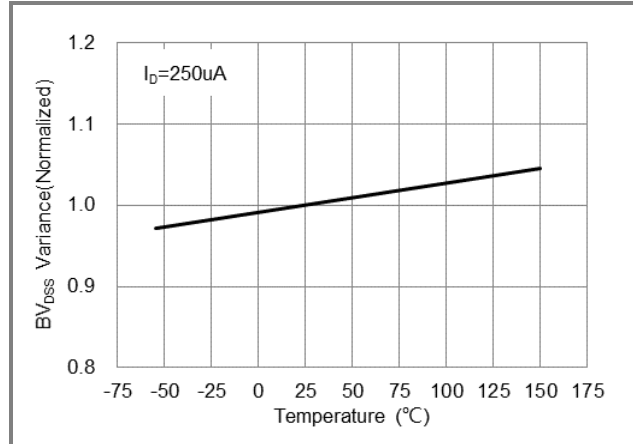


Fig.8 Breakdown Voltage Variation vs. Temperature

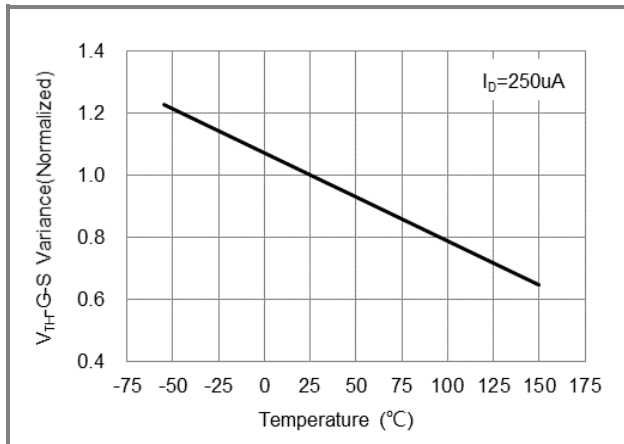


Fig.9 Threshold Voltage Variation with Temperature

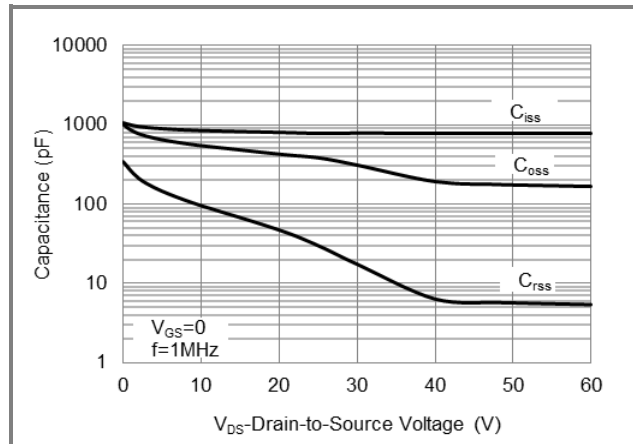


Fig.10 Capacitance vs. Drain-Source Voltage

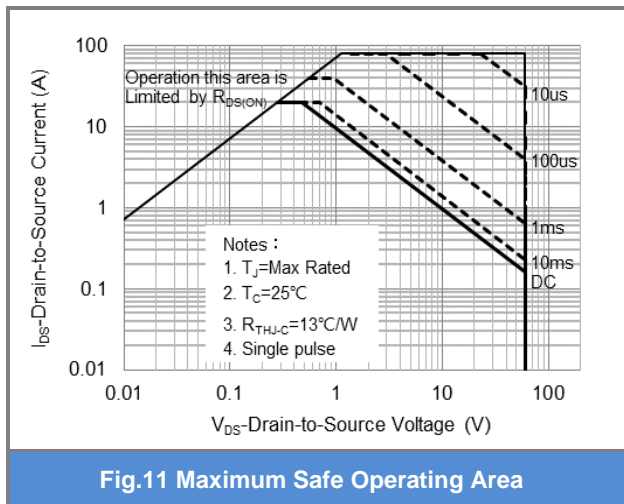


Fig.11 Maximum Safe Operating Area

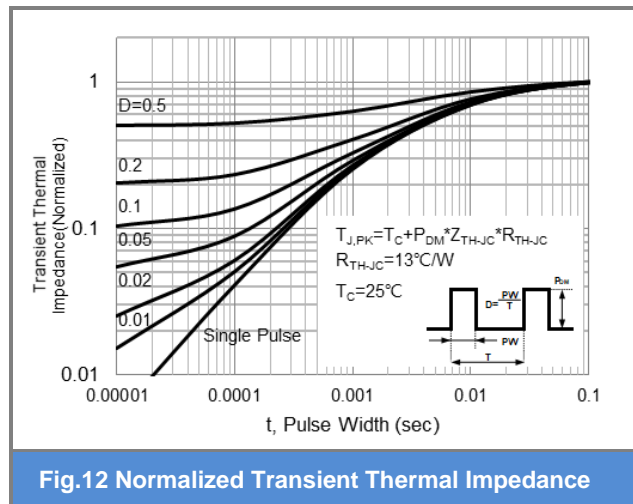


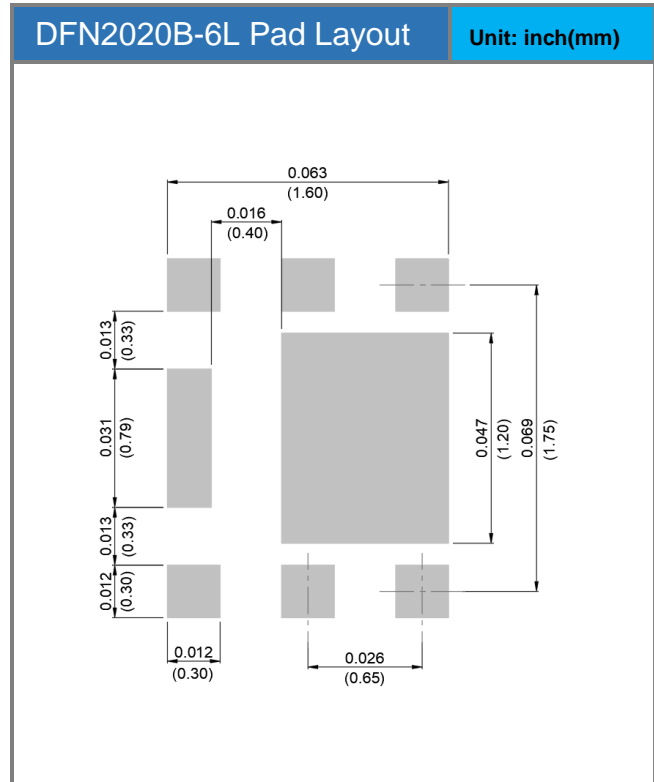
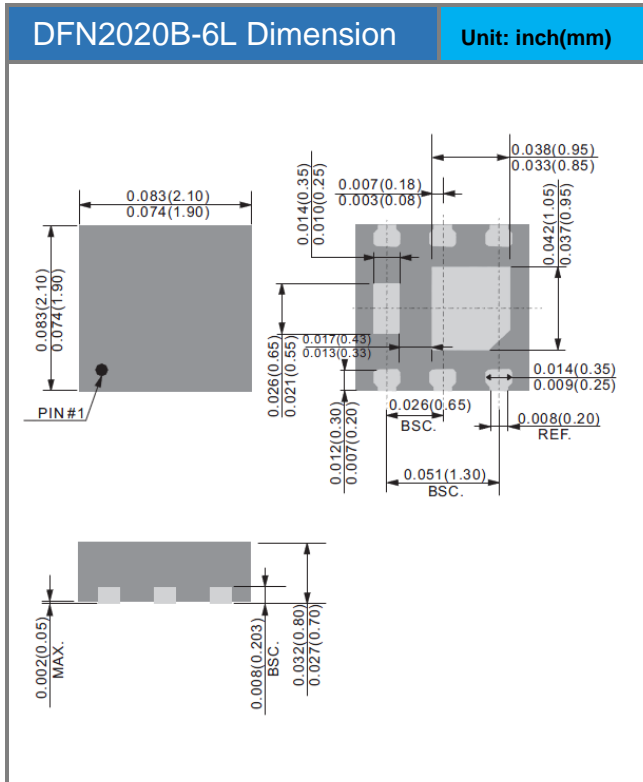
Fig.12 Normalized Transient Thermal Impedance

PJQ2566A

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ2566A	DFN2020B-6L	3K pcs / 7" reel	566

Packaging Information & Mounting Pad Layout



PJQ2566A

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[1N4148-35_AY_10001](#) [1N4148W-AU_R1_00001](#) [1N4148W-AU_R1_000A1](#) [1N4148W_R1_00001](#) [1N4148W_R1_000A7](#)
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